



High voltage fast-switching NPN power transistor

Features

- High voltage capability
- Low spread of dynamic parameters
- Very high switching speed

Application

■ Compact fluorescent lamps (CFLs)

Description

The device is manufactured using high voltage multi epitaxial planar technology for high switching speeds and high voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA.

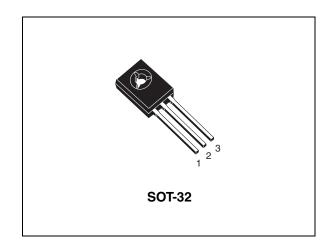


Figure 1. Internal schematic diagram

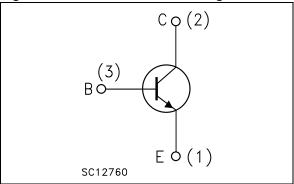


Table 1. Device summary

Order code	Marking	Package	Packaging
ST13003N	13003N	SOT-32	BAG

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Electrical ratings ST13003N

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit	
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	700	V	
V _{CEO}	Collector-emitter voltage (I _B = 0)	400	V	
V _{EBO}	Collector-base voltage (I _C = 0)	9	V	
I _C	Collector current	1	Α	
I _{CM}	Collector peak current (t _P < 5 ms)	2	Α	
I _B	Base current	0.5	Α	
I _{BM}	Base peak current (t _P < 5 ms)	1	Α	
P _{TOT}	Total dissipation at T _C = 25 °C	20	W	
T _{STG}	Storage temperature	-55 to 150	°C	
TJ	Max. operating junction temperature	150	J	

Table 3. Thermal data

	Symbol	Parameter	Value	Unit
Ī	R_{thJC}	Thermal resistance junction-case	6.25	°C/W

2 Electrical characteristics

 T_{case} = 25 °C; unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BF} = 0)	$V_{CE} = 700 \text{ V}$ $V_{CF} = 700 \text{ V}$ $T_{C} = 125$	°C		1 5	mA mA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 9 V			1	mA
V _{CEO(sus)}	Collector-emitter sustaining voltage (I _B = 0)	I _C = 10 mA	400			V
V _{CE(sat)} (1)	Collector-emitter saturation voltage	$I_C = 0.5 \text{ A}$ $I_B = 125 \text{ m/s}$ $I_C = 1 \text{ A}$ $I_B = 330 \text{ m/s}$			0.7 1.2	V V
V _{BE(sat)} (1)	Base-emitter saturation voltage	$I_C = 0.5 \text{ A}$ $I_B = 125 \text{ m/s}$ $I_C = 1 \text{ A}$ $I_B = 330 \text{ m/s}$			1.2 1.3	V V
h _{FE}	DC current gain	$I_C = 0.5 \text{ A},$ $V_{CE} = 2 \text{ V}$ $I_C = 1 \text{ A}$ $V_{CE} = 10 \text{ V}$	6 5		18 15	
t _s t _f	Inductive Load Storage time Fall time	$\begin{split} I_{C} &= 0.4 \text{ A} V_{clamp} = 300 \text{ V} \\ I_{B(on)} &= -I_{B(off)} = 80 \text{ mA} \\ V_{BB(off)} &= -5 \text{ V} \qquad \qquad \textit{Figure} \end{split}$	9 8	2.5 180		μs ns

^{1.} Pulse test: pulse duration $\leq 300~\mu s,$ duty cycle $\leq 2~\%$

2.1 Electrical characteristics (curves)



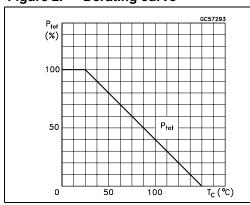
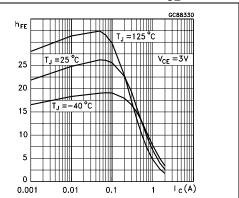


Figure 3. DC current gain $(V_{CE} = 3 V)$



Electrical characteristics ST13003N

Figure 4. DC current gain (V_{CE} = 5 V) Figure 5. Collector-emitter saturation voltage

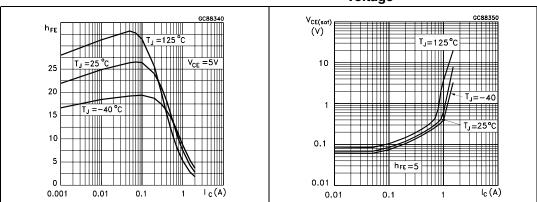
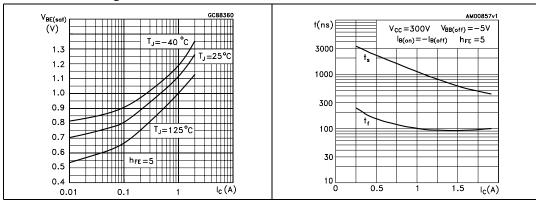


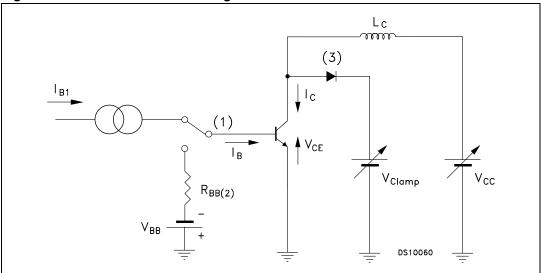
Figure 6. Base-emitter saturation voltage

Figure 7. Switching time inductive load



2.2 Test circuit

Figure 8. Inductive load switching test circuit



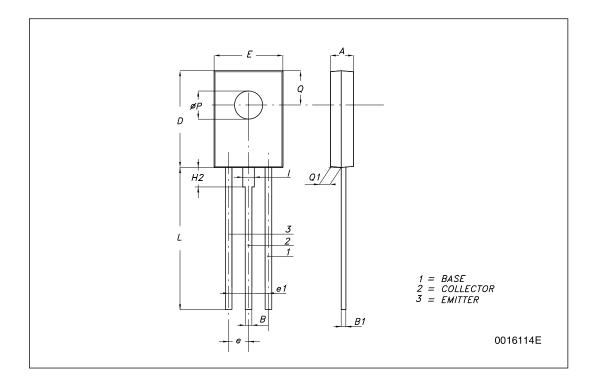
- 1. Fast electronic switch
- 2. Non-inductive resistor
- 3. Fast recovery rectifier

3 Package mechanical data

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DIM.	mm.			
DIIVI.	MIN.	TYP	MAX.	
Α	2.4		2.9	
В	0.64		0.88	
B1	0.39		0.63	
D	10.5		11.05	
Е	7.4		7.8	
е	2.04	2.29	2.54	
e1	4.07	4.58	5.08	
L	15.3		16	
Р	2.9		3.2	
Q		3.8		
Q1	1		1.52	
H2		2.15		
I		1.27		





Revision history ST13003N

4 Revision history

Table 5. Document revision history

Date	Revision	Changes
26-May-2009	1	First release.
25-Feb-2010	2	Updated Figure 1 on page 1.

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